

W(Typ) D(Typ) H(Max)

2ch High Side Switch ICs

Current Limit High Side Switch ICs

BD6516F BD6517F BD2042AFJ BD2052AFJ

General Description

BD6516F, BD6517F, BD2042AFJ and BD2052AFJ are dual channel high side switch ICs with an over current protection for Universal Serial Bus (USB) power supply line. The IC's switch unit has two channels of N-Channel power MOSFET. Over current detection circuit, thermal shutdown circuit, under voltage lockout and soft start circuit are built in.

Features

- **Dual N-MOS High Side Switch**
- **Control Input Logic**
 - BD6517F, BD2042AFJ Active-Low: \triangleright
 - Active-High: BD6516F, BD2052AFJ
- Soft Start Circuit
- **Over Current Detection**
- Thermal Shutdown
- Under Voltage Lockout
- Open Drain Error Flag Output
- Reverse-Current Protection when Switch Off
- Flag Output Delay

Applications

USB Hub in Consumer Appliances, Note PC, PC Peripheral Equipment, and so on.

Typical Application Circuit

Key Specifications

Input Voltage Range:	
BD6516F/BD6517F	3.0V to 5.5V
BD2042AFJ/BD2052AF	J 2.7V to 5.5V
ON-Resistance:	
BD6516F/BD6517F	110mΩ(Typ)
BD2042AFJ/BD2052AF	J 100mΩ(Typ)
Continuous Current:	0.5A
Current Limit Threshold:	
BD6516F/BD6517F	1.2A(Min), 2.5A (Max)
BD2042AFJ/BD2052AF	J 0.7A(Min), 1.8A (Max)
Standby Current:	0.01µA (Typ)
Output Rise Time:	1.8ms (Typ)
Operating Temperature Ratio	ange:
BD6516F/BD6517F	-25°C to +85°C
BD2042AFJ/BD2052AF	J -40°C to +85°C

Packages





Lineup

Curre	Current Limit Threshold		Control Innut Logio		akasa	Ordereble Dort Number	
Min	Тур	Max		Раскаде		Orderable Part Number	
1.2A	1.65A	2.5A	High	000		BD6516F-E2	
1.2A	1.65A	2.5A	Low	5098	Deal of 2500	BD6517F-E2	
0.7A	1.0A	1.8A	High		Reel 01 2500	BD2052AFJ-E2	
0.7A	1.0A	1.8A	Low	20P-J8		BD2042AFJ-E2	

OProduct structure : Silicon monolithic integrated circuit OThis product has not designed protection against radioactive rays

Block Diagrams





Pin Configurations



BD2042AFJ/BD2052AFJ



BD2042AFJ/BD2052AFJ TOP VIEW

1	GND	/OC1	8
2	IN	OUT1	7
3	/EN1 (FN1)	OUT2	6
4	/EN2 (EN2)	/OC2	5
	()		

BD2042AFJ/BD2052AFJ

Pin Descriptions

BD6516F/BD6517F

Pin No.	Symbol	1/0	Pin Function	Pin No.	Symbol	I/O	Pin Function
1, 4	CTRLA CTRLB	I	Enable input. Switch on at low level. (BD6517F) Low level input < 0.7V. Switch on at high level. (BD6516F) High level input > 2.5V.	1	GND	I	Ground.
2, 3	FLAGA FLAGB	ο	Error flag output. Low at over current, thermal shutdown. Open drain output.	2	IN	I	Power supply input. Input terminal of the switch and power supply of internal circuit.
5, 8	OUTA OUTB	0	Switch output.	3, 4	/EN1 /EN2, EN1 EN2	I	Enable input. /EN: Switch on at low level. (BD2042AFJ) Low level input < 0.8V EN: Switch on at high level. (BD2052AFJ) High level input > 2.0V.
6	GND	I	Ground.	5, 8	/OC2 /OC1	0	Error flag output. Low at over current, thermal shutdown. Open drain output.
7	VDD	I	Power supply input. Input terminal of the switch and power supply of internal circuit.	6, 7	OUT2 OUT1	0	Switch output.

Absolute Maximum Ratings BD6516F/BD6517F

Parameter	Symbol	Rating	Unit
Input Voltage	Vdd	-0.3 to +6.0	V
CTRL Voltage	VCTRL	-0.3 to V _{DD} +0.3	V
FLAG Voltage	Vflag	-0.3 to +6.0	V
Output Voltage	Vout	-0.3 to +6.0	V
Storage Temperature	Tstg	-55 to +150	°C
Power Dissipation	Pd	0.67 ^(Note 1)	W

BD2042AFJ/BD2052AFJ

Parameter	Symbol	Rating	Unit
Input Voltage	VIN	-0.3 to +6.0	V
EN, /EN Voltage	Ven, V/en	-0.3 to +6.0	V
/OC Voltage	V/oc	-0.3 to +6.0	V
/OC Current	Is/oc	10	mA
OUT Voltage	Vout	-0.3 to +6.0	V
Storage Temperature	Tstg	-55 to +150	°C
Power Dissipation	Pd	0.67 (Note 1)	W

(Note 1) Mounted on 70mm x 70mm x 1.6mm glass-epoxy PCB. Derating : 5.4mW/°C above Ta=25 °C

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operation Conditions

BD6516F/BD6517F

Parameter	Symbol		Linit			
Falameter	Symbol	Min Typ Max		Max		
Input Voltage	V_{DD}	3.0	-	5.5	V	
Operation Temperature	Topr	-25	-	+85	°C	
Continuous Output Current	I _{LO}	0	-	500	mA	

BD2042AFJ/BD2052AFJ

Paramotor	Symbol		Llnit			
Falametei	Symbol	Min	Min Typ Max		Unit	
Input Voltage	V _{IN}	2.7	-	5.5	V	
Operation Temperature	Topr	-40	-	+85	°C	
Continuous Output Current	I _{LO}	0	-	500	mA	

Electrical Characteristics

BD6516F/BD6517F (V_{DD}=5V, Ta=25 °C, unless otherwise specified.)

Deremeter	Symbol	Limit		Lloit	Conditions	
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Operating Current	I _{DD}	-	100	140	μA	V _{CTRL} =5V(BD6516F), 0V(BD6517F) OUT=OPEN
Standby Current	I _{STB}	-	0.01	2	μA	V _{CTRL} =0V(BD6516F), 5V(BD6517F) OUT=OPEN
	V	-	-	0.7	V	Low Level Input Voltage
CTIL Input Voltage	VCIRL	2.5	-	-	V	High Level Input Voltage
CTRL Input Current		-1	+0.01	+1	μA	V _{CTRL} =0V or 5V
FLAG Output Resistance	R_{FLAG}	-	250	450	Ω	I _{FLAG} =1mA
FLAG Output Leak Current	I _{FLAG}	-	0.01	1	μA	V _{FLAG} =5V
FLAG Output Delay	t/FL	-	1	4	ms	
ON Posistance	Б	-	110	150	mΩ	V _{DD} =5V, I _{OUT} =500mA
ON-Resistance	RON	-	140	180	mΩ	V _{DD} =3.3V, I _{OUT} =500mA
Over-Current Threshold	I _{TH}	1.2	1.65	2.5	А	
Short Circuit Output Current	I _{SC}	1.2	1.65	2.2	А	V _{OUT} =0V
Output Leak Current	I _{LEAK}	-	-	10	μA	V _{CTRL} =0V(BD6516F), 5V(BD6517F)
Thermal Shutdown Threshold	T_{TS}	-	135	-	°C	At Tj Increase
Output Rise Time	t _{ON1}	0.1	1.3	4.0	ms	R _L =10Ω
Output Turn ON Delay Time	t _{ON2}	0.2	1.5	6.0	ms	$R_L=10\Omega$
Output Fall Time	t _{OFF1}	-	1	20	μs	R _L =10Ω
Output Turn OFF Delay Time	t _{OFF2}	-	3	20	μs	R _L =10Ω

BD2042AFJ/BD2052AFJ (V_{DD} =5V, Ta=25 °C, unless otherwise specified.)

Deremeter	Symbol	Limit			Linit	Conditiono	
Parameter	Symbol	Min	Тур	Max	Unit	Conditions	
Operating Current	I _{DD}	-	110	140	μA	$V_{/EN}$ = 0V, OUT = OPEN (BD2042AFJ) V_{EN} = 5V, OUT = OPEN (BD2052AFJ)	
Standby Current	I _{STB}	-	0.01	1	μA	$V_{/EN}$ = 5V, OUT = OPEN (BD2042AFJ) V_{EN} = 0V, OUT = OPEN (BD2052AFJ)	
	V _{/ENH} , V _{ENH}	2.0	-	-	V	High Input	
/EN, EN Input Voltage	V _{/ENL} ,	-	-	0.8	V	Low Input	
	V_{ENL}	-	-	0.4	V	Low Input 2.7V \leq V _{IN} \leq 4.5V	
/EN, EN Input Current	$I_{/EN}, I_{EN}$	-1.0	+0.01	+1.0	μA	$V_{\rm /EN}, V_{\rm EN}$ = 0V or $V_{\rm /EN}, V_{\rm EN}$ = 5V	
/OC Output Low Voltage	V _{/OC}	-	-	0.5	V	I _{/OC} = 5mA	
/OC Output Leak Current	I _{L/OC}	-	0.01	1	μA	V _{/OC} = 5V	
ON-Resistance	R _{ON}	-	100	130	mΩ	I _{OUT} = 500mA	
Over-Current Threshold	I _{TH}	0.7	1.0	1.8	Α		
Short Circuit Output Current	I _{SC}	0.7	1.0	1.3	А	V_{IN} = 5V, V_{OUT} = 0V, C_L = 100µF (RMS)	
Output Rise Time	t _{ON1}	-	1.8	10	ms		
Output Turn ON Time	t _{ON2}	-	2.1	20	ms		
Output Fall Time	t _{OFF1}	-	1	20	μs	$-R_L = 10\Omega$, $C_L = OPEN$	
Output Turn OFF Time	t _{OFF2}	-	3	40	μs		
	V _{TUVH}	2.1	2.3	2.5	V	Increasing V _{IN}	
	V _{TUVL}	2.0	2.2	2.4	V	Decreasing V _{IN}	

Measurement Circuits





C. ON-Resistance, Over Current Detection





E. Operating Current



G. ON-Resistance, Over Current Detection





B. CTRL Input Voltage, Output Rise / Fall Time



D. FLAG Output Resistance



F. EN, /EN Input Voltage, Output Rise / Fall Time



H. /OC Output Low Voltage

Timing Diagram





Typical Performance Curves BD6516F/ BD6517F



Figure 6. Standby Current vs Ambient Temperature

Supply Voltage











Figure 16. Output Turn ON Delay Time vs Ambient Temperature







Figure 18. Output Fall Time vs Ambient Temperature





Current vs Supply Voltage







Figure 24. FLAG Output Resistance vs Ambient Temperature







Figure 26. FLAG Output Delay vs Ambient Temperature

Typical Performance Curves - continued BD2042AFJ/ BD2052AFJ





vs Supply Voltage

Figure 34. /OC Output Low Voltage vs Ambient Temperature











Typical Wave Forms



Typical Wave Forms - continued



Regarding the output rise/fall and over current detection characteristics of BD6517F, BD2042AFJ refer to the characteristic of BD6516F, BD2052AFJ.

Typical Application Circuit



Application Information

Excessive current flow due to output short circuit, or so, may induce ringing because of the presence of an inductance between the supply line and IC. This event may cause IC malfunction during operation. To avoid this, connect a bypass capacitor between IN and GND pins. 1μ F or higher is recommended.

Pull up flag output (/OC) by resistance value from $10k\Omega$ to $100k\Omega$.

Set up values of C_L which satisfies the application.

The application circuit above does not guarantee its operation.

When using the circuit with changes to the external circuit constants, make sure to leave an adequate margin for external components including AC/DC characteristics as well as IC transient characteristics.

Functional Description

1. Switch Operation

VDD(IN) pin and OUT pin are connected to the drain and the source of switch MOSFET respectively. The VDD(IN) pin is also used as a power source for internal control circuit.

When the switch is turned on from CTRL(EN) control input, VDD(IN) and OUT are connected. In a normal condition, current flows from VDD to OUT. If the voltage at OUT is higher than VDD, current flows from OUT to VDD since the There is no parasitic diode and it is possible to prevent current flow from OUT to VDD(IN).

2. Thermal Shutdown (TSD)

Thermal shutdown circuit turns off the switch and outputs an error flag when the junction temperature in the chip exceeds a threshold temperature. The thermal shutdown circuit works when either of the two control signals is active.

In BD6516F/BD6517F, the switches of both OUTA and OUTB turn off and output error flags; BD2042AFJ/ BD2052AFJ has dual threshold temperature for its thermal shutdown. Since thermal shutdown works at a lower junction temperature, only the switch with an over current state turns off whenever over current occurs and outputs an error flag.

Thermal shutdown detection has hysteresis. Therefore, when the junction temperature goes down, switch turns on and error flag is cancelled. Unless the increase of the chip's temperature is removed or the output of power switch is turned off, this operation repeats.

3. Over-Current Detection/Limit Circuit

The over current detection circuit limits current (I_{SC}) and outputs an error flag (/OC) when current flowing in each switch MOSFET exceeds a specified value. There are three types of response against over current. The over current detection circuit works when the switch is on (CTRL, EN signal is active).

- (1) When the switch is turned on while the output is in short-circuit status, the switch goes into current limit status immediately.
- (2) When the output short-circuits or high-current load is connected while the switch is on, very large current flows until the over current limit circuit reacts. When the current detection and limit circuit works, current limitation is carried out.
- (3) When the output current increases gradually, current limitation does not work until the output current exceeds the over current detection value. When it exceeds the detection value, current limitation is carried out.
- 4. Under Voltage Lockout (UVLO)

UVLO circuit turns off the switch to prevent malfunction when the supply voltage is below the UVLO threshold level, The UVLO circuit works when either of two control signals is active.

OBD2042AFJ/BD2052AFJ

UVLO circuit prevents the switch from turning on until the V_{IN} exceeds 2.3V(Typ). If the V_{IN} drops below 2.2V(Typ) while the switch is ON, then UVLO shuts OFF the switch. UVLO has hysteresis of 100mV(Typ).

5. Error Flag (/OC) Output

Error flag output is an N-MOS open drain output.

At detection of over current limit and thermal shutdown, /OC outputs a low level signal. Error flag output (/OC) at over current detection has a delay filter. This delay filter prevents instantaneous current detection such as inrush current at switch ON, or applying external power supplies. If fault flag output is unused, /OC pin should be connected to open or ground line.



Figure 61. BD6516F/ BD6517F/BD2042AFJ/ BD2052AFJ Over Current Detection, Thermal Shutdown Timing Diagram (V_{CTRL}, V_{/EN} of BD6517F/BD2042AFJ Active Low)

Power Dissipation

(SOP8, SOP-J8)



70mm x 70mm x 1.6mm Glass Epoxy Board

Figure 62. Power Dissipation Curve

I/O Equivalence Circuit

BD6516F/BD65	517F	
Symbol	Pin No.	Equivalence Circuit
CTRLA CTRLB	1, 4	
FLAGA FLAGB	2, 3	FLAGA FLAGB
OUTA OUTB	5, 8	

BD2042AFJ/BD2052AFJ

Symbol	Pin No	Equivalence Circuit
/EN1(EN1) /EN2(EN2)	3, 4	/EN1(EN1) /EN2(EN2)
/0C1 /0C2	5, 8	
OUT1 OUT2	6, 7	

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. In rush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes - continued

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate lavers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



Figure 63. Example of monolithic IC structure

13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

14. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

15. Thermal design

Perform thermal design in which there are adequate margins by taking into account the power dissipation (Pd) in actual states of use.



Marking Diagrams



	Part Number Marking
	LOT Number
	<u>1PIN MARK</u>

Part Number	Part Number Marking	
BD6516F	D6516	
BD6517F	D6517	

Part Number	Part Number Marking	
BD2042AFJ	D042A	
BD2052AFJ	D052A	

SOP-J8 (TOP VIEW)





Physical Dimension, Tape and Reel Information – continued Package Name SOP-J8 4. 9 ± 0.2 $4^{\circ}{}^{+6^{\circ}}_{-4^{\circ}}$ Max 5. 25 (include. BURR) 7 8 6 5 3 2 9 ± 0 . 0=0. .9 ŝ 45MIN 0 2 1 0.545 0.2 ± 0.1 S - $375\pm0.$ i. (UNIT:mm) ß PKG:SOP-J8 17 Drawing No. EX111-5002 0.42 ± 0.1 1. 27 0. □ 0. 1 S <Tape and Reel information> Таре Embossed carrier tape 2500pcs Quantity E2 Direction (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed 0 0 0 \cap \cap \cap \cap С Direction of feed 1pin `Reel *Order quantity needs to be multiple of the minimum quantity.

Revision History

Date	Revision	Changes
11.Mar.2013	001	New Release
25.Jun.2013 002 Changed character color from RED to BLACK on page 6.		Changed character color from RED to BLACK on page 6.
21.Aug.2014	003	Applied the ROHM Standard Style and improved understandability. Delete BD6512F and BD6513F.

Notice

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	1 1		
JAPAN	USA	EU	CHINA
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CLASSⅣ		CLASSⅢ	CLASSIII

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [C] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

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